NSN 5961-01-175-8449

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-175-8449 **Inclosure Material:** Metal **Overall Length:** 0.070 inches **Overall Diameter:** 0.122 inches **End Application:** An/srq-4 radio-telemetric data set **Mounting Method:** Press fit **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 reverse voltage, dc **Current Rating Per Characteristic:** 2.00 microamperes forward current, average peak **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Terminal Type And Quantity:** 1 uninsulated wire lead and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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